

March 1995

### **LM1877 Dual Audio Power Amplifier**

### **General Description**

The LM1877 is a monolithic dual power amplifier designed to deliver 2W/channel continuous into  $8\Omega$  loads. The LM1877 is designed to operate with a low number of external components, and still provide flexibility for use in stereo phonographs, tape recorders and AM-FM stereo receivers, etc. Each power amplifier is biased from a common internal regulator to provide high power supply rejection, and output Q point centering. The LM1877 is internally compensated for all gains greater than 10.

### **Features**

- 2W/channel
- -65 dB ripple rejection, output referred
- -65 dB channel separation, output referred

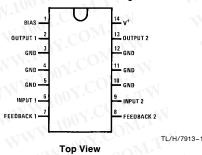
- Wide supply range, 6V-24V
- Very low cross-over distortion
- Low audio band noise
- AC short circuit protected
- Internal thermal shutdown

### **Applications**

- Multi-channel audio systems
- Stereo phonographs
- Tape recorders and players
- AM-FM radio receivers
- Servo amplifiers
- Intercom systemsAutomotive products

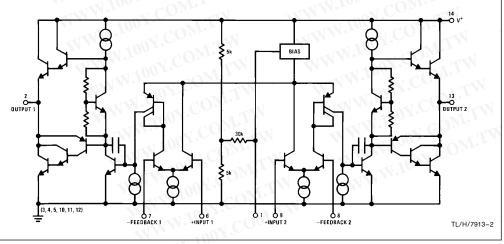
### **Connection Diagram**

Dual-In-Line Package or Surface Mount Package



Order Number LM1877M-9 or LM1877N-9 See NS Package Number M14B or N14A

### **Equivalent Schematic Diagram**



WWW.100Y.COM.TW **Absolute Maximum Ratings** 

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If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

N-Package Soldering (10 sec.) M-Package Infared (15 sec.) M-Package Vapor Phase (60 sec.) 260°C 220°C

Supply Voltage 26V Input Voltage

±0.7V

150°C

215°C

**Operating Temperature** Storage Temperature Junction Temperature

0°C to +70°C -65°C to +150°C

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θ<sub>JC</sub> (N-Package) θ<sub>JA</sub> (N-Package)  $\theta_{JC}$  (M-Package)  $\theta_{JA}$  (M-Package)

Thermal Resistance

Lead Temperature

30°C/W 79°C/W ∠/°C/W 114°C/W 27°C/W

### **Electrical Characteristics**

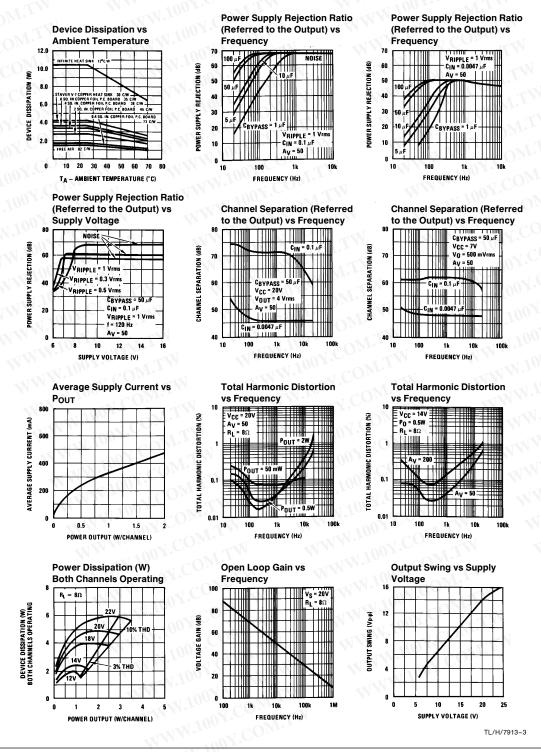
 $V_S=$  20V,  $T_A=$  25°C, (See Note 1)  $R_L=$  8 $\Omega$ ,  $A_V=$  50 (34 dB) unless otherwise specified

Parameter	Conditions	Min	Тур	Max	Units
Total Supply Current	$P_0 = 0W$	T.T.	25	50	mA
Output Power LM1877	THD = 10% $V_S = 20V, R_L = 8\Omega$ $V_S = 12V, R_L = 8\Omega$	2.0	1.3	MM	W/Ch W/Ch
Total Harmonic Distortion LM1877	f = 1 kHz, V <sub>S</sub> = 14V	OM.T	W	WW	NW.1
	P <sub>O</sub> = 50 mW/Channel	Mo	0.075		%
	P <sub>O</sub> = 500 mW/Channel	Con	0.045	1	%
	P <sub>O</sub> = 1 W/Channel	$_{\rm J}$ ${ m CO}^{ m N}$	0.055		%
Output Swing	$R_L = 8\Omega$	7	V <sub>S</sub> -6		Vp-p
Channel Separation	$C_F = 50 \mu F$ , $C_{IN} = 0.1 \mu F$ , f = 1 kHz, Output Referred	97.C	MIM	(I	W V
	$V_S = 20V, V_O = 4 \text{ Vrms}$	-50	-70		dB
	$V_S = 7V$ , $V_O = 0.5$ Vrms	1007.	-60	7	dB
PSRR Power Supply Rejection Ratio	$C_F = 50 \mu F, C_{IN} = 0.1 \mu F,$ f = 120 Hz, Output Referred	1.1001	COM	IM	
	$V_S = 20V, V_{RIPPLE} = 1 Vrms$	-50	-65	TW	dB
	$V_S = 7V$ , $V_{RIPPLE} = 0.5 V rms$	W.r	-40	W	dB
Noise	Equivalent Input Noise	UW.10	-1 CO	17.7	
	$\begin{aligned} &R_S = 0, C_{\text{IN}} = 0.1  \mu\text{F}, \\ &BW = 20  \text{Hz} - 20  \text{kHz}, \text{Output Noise Wideband} \end{aligned}$	WW.1	2.5	MIL	μ۷
	$R_S = 0, C_N = 0.1 \mu F, A_V 200$	W.	0.80	$O_{M^{-1}}$	mV
Open Loop Gain	$R_S = 0$ , $f = 100$ kHz, $R_L = 8\Omega$	N	70	Mo	dB
Input Offset Voltage	WWW. DOX.CO. TW	MW	15	O s	mV
Input Bias Current	COM.	WIN	50	$CO_{N_2}$	nA
Input Impedance	Open Loop	NA .	4	LC01	МΩ
DC Output Level	$V_S = 20V$	9	10	- 11	V
Slew Rate	WIND ON COM	1	2.0	ov.Ct	V/μs
Power Bandwidth	COM.		65	<1 C	kHz
Current Limit	WY 100X.		1.0	00 7.	Α

Note 1: For operation at ambient temperature greater than 25°C, the LM1877 must be derated based on a maximum 150°C junction temperature. WW.100Y.CO EWW.100Y.COM.TW

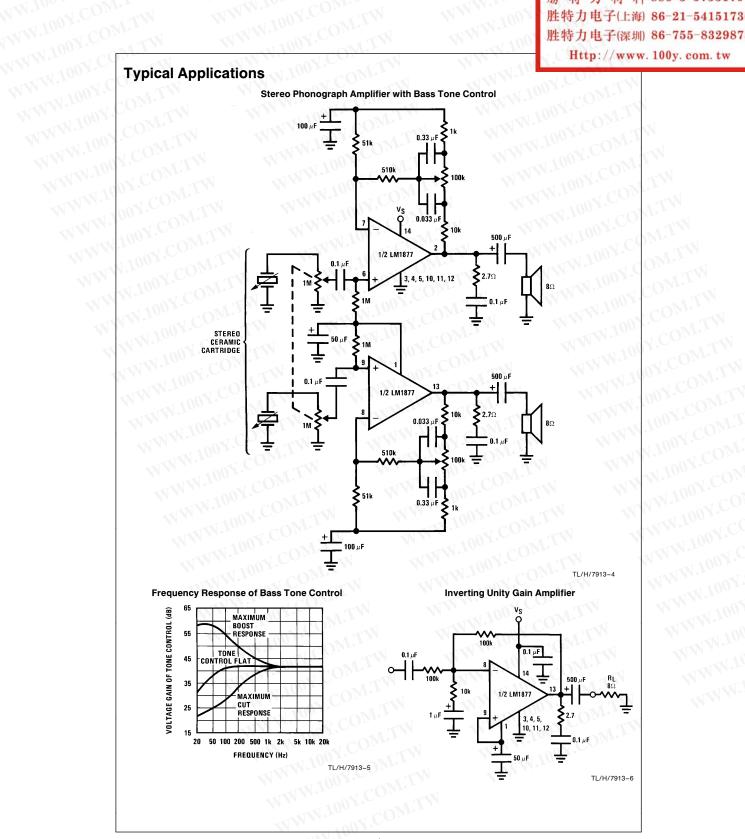
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# Typical Performance Characteristics



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# WWW.100Y.COM.TW Typical Applications (Continued)

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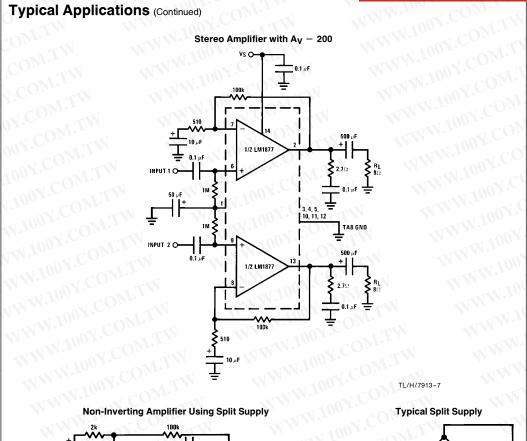
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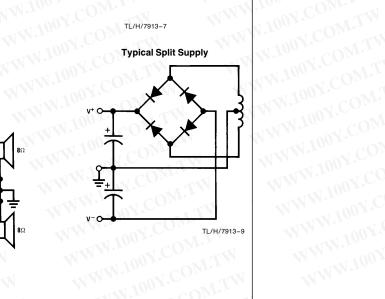
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#### Stereo Amplifier with A<sub>V</sub> = 200



### Non-Inverting Amplifier Using Split Supply

[7] 14 1/2 LM1877 v<sub>L</sub> 0 → ( **≥**2.7Ω 0.1 10, 11, 12 2.7Ω 0.1 μΕ 1/2 LM1877 WWW.100Y.COM.TW WWW.100Y.COM.TW TL/H/7913-8



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## WW.100Y.COM.TW Physical Dimensions inches (millimeters) 0.346 - 0.362 (8.788 - 9.195) 14 13 12 11 10 9 8 H H H H H H H LEAD NO. 1 IDENT H H H H H H 1 2 3 4 5 6 7 0.291 - 0.299 (7.391 - 7.595) $\frac{0.093-0.104}{(2.362-2.642)}$ 0.004 - 0.012 (0.102 - 0.305) 1 Molded SOIC Package (M) Order Number LM1877M-9 NS Package Number M14B 0.740 - 0.770 118 80 - 19 56) 14 13 12 0.250 ± 0.010 (6.350 ± 0.254) 1234567 0.092 (2.337) DIA 0.030 MAX (0.782) DEP7H 0.065 (1.651) € 0.060 (1.524) TYP 0.125 - 0.150 (3.175 - 3.610) 0.075±0.015 (1 905±0.381) 0.280 (7.112) MIN 0.014 - 0.023 (0.356 - 0.584) TYP

### Order Number LM1877N-9 **NS Package Number N14A**

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Molded Dual-In-Line Package (N)

0.050 ± 0.010 (1.270 - 0.254)

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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